

United States Patent and Trademark Office



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.usplo.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/528,725	03/22/2005	Alastair Robert Buckley	BHJ8USA	6955
270 7	590 11/30/2006		EXAMINER	
HOWSON AND HOWSON			HINES, ANNE M	
SUITE 210 501 OFFICE CENTER DRIVE			ART UNIT	PAPER NUMBER
FT WASHINGTON, PA 19034			2879	

DATE MAILED: 11/30/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/528,725	BUCKLEY, ALASTAIR ROBERT			
Office Action Summary	Examiner	Art Unit			
	Anne M. Hines	2879			
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPLY WHICHEVER IS LONGER, FROM THE MAILING DA - Extensions of time may be available under the provisions of 37 CFR 1.13 after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period w - Failure to reply within the set or extended period for reply will, by statute, Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 16(a). In no event, however, may a reply be tim iill apply and will expire SIX (6) MONTHS from cause the application to become ABANDONEI	I. lely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
Responsive to communication(s) filed on 22 March 2a) This action is FINAL. 2b) This Since this application is in condition for allowant closed in accordance with the practice under E	action is non-final. ace except for formal matters, pro				
Disposition of Claims					
4) ⊠ Claim(s) 1-3,9,10 and 19-33 is/are pending in to 4a) Of the above claim(s) is/are withdraw 5) □ Claim(s) is/are allowed. 6) ⊠ Claim(s) 1-3,9,10 and 19-33 is/are rejected. 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and/or	vn from consideration.				
Application Papers					
9) ☐ The specification is objected to by the Examine 10) ☑ The drawing(s) filed on 22 March 2005 is/are: a Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11) ☐ The oath or declaration is objected to by the Ex	a)⊠ accepted or b)☐ objected to drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). jected to. See 37 CFR 1.121(d).			
Priority under 35 U.S.C. § 119		·			
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.					
Attachment(s)					
1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO/SB/08) Paper No(s)/Mail Date 10/3/05.	4) Interview Summary Paper No(s)/Mail Do 5) Notice of Informal P 6) Other:	ate			

Art Unit: 2879

DETAILED ACTION

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1, 2, 9, 10, 19, and 21-24 are rejected under 35 U.S.C. 102(b) as being anticipated by Sakai et al. (EP 1199909 A9) (of record).

Regarding claim 1, Sakai discloses an organic light emitting diode device having a passivation layer comprising boron oxide (Pages 17-18, Paragraphs [0164]-[0165]; Page 16, Paragraph [0145]).

Regarding claim 2, Sakai further discloses wherein the device comprises a substrate, a layer of organic light emitting material, and a transparent cathode comprising a layer of material with a work function less than 4 eV (Pages 17-18, Paragraphs [0164]-[0165]; Page 16, Paragraph [0140]; Figs. 5 and 6).

Regarding claim 9, Sakai discloses a method of manufacturing an organic light emitting diode device, comprising depositing a passivation layer comprising boron oxide on the device (Pages 17-18, Paragraphs [0164]-[0165]; Page 16, Paragraph [0145]; Fig. 6, 3).

Art Unit: 2879

Regarding claim 10, Sakai further discloses wherein the passivation layer is deposited by thermal evaporation (Page 16, Paragraphs [0145]-[0146]).

Regarding claim 19, Sakai discloses a passivation layer for an electronic device comprising boron oxide (Pages 17-18, Paragraphs [0164]-[0165]; Page 16, Paragraph [0145]).

Regarding claim 21, Sakai further discloses wherein the passivation layer directly overlies the layer of material with a work function less than 4 eV (Page 15, Paragraph [0137]; Figs. 5 and 6; Pages 17-18, Paragraphs [0164]-[0165]).

Regarding claim 22, Sakai further discloses wherein an encapsulation layer overlies the passivation layer (Pages 17-18, Paragraphs [0164]-[0165]—see sealing member; Figs. 5 and 6).

Regarding claim 23, Sakai further discloses wherein the encapsulating layer is SiO₂ (Page 13, Paragraph [0110]). Note that the Examiner understands that quartz is inherently SiO₂.

Regarding claim 24, Sakai further discloses wherein the device further comprises sealing layers of adhesive and glass (Pages 17-18, Paragraphs [0164]-[0165]---see sealing member; Figs. 5 and 6; Page 13, Paragraph [0107]).

Claims 1-3, 9, 10, 19-22, 24, 26-29, and 32-33 are rejected under 35 U.S.C. 102(e) as being anticipated by Stegamet (US 2004/0046500).

Art Unit: 2879

Regarding claim 1, Stegamet discloses an organic light emitting diode device having a passivation layer comprising boron oxide (Figs. 1 and 2; Page 2, Paragraph [0030]; Page 3, Paragraph [000051]; Page 5, Paragraph [0078]).

Regarding claim 2, Stegamet further discloses wherein the device comprises a substrate, a layer of organic light emitting material, and a transparent cathode comprising a layer of material with a work function less than 4 eV (Page 2, Paragraph [0030]; Page 2, Paragraph [0034]; Page 4, Paragraphs [0063]-[0064]).

Regarding claim 3, Stegamet further discloses wherein the material with a work function of less than 4 eV is calcium (Page 4, Paragraph [0064]).

Regarding claim 9, Stegamet discloses a method of manufacturing an organic light emitting diode device, comprising depositing a passivation layer comprising boron oxide on the device (Figs. 1 and 2; Page 2, Paragraph [0030]; Page 3, Paragraph [000051]; Page 5, Paragraph [0078]).

Regarding claim 10, Stegamet further discloses wherein the passivation layer is deposited by thermal evaporation (Page 5, Paragraph [0072]).

Regarding claim 19, Stegamet discloses a passivation layer for an electronic device comprising boron oxide (Figs. 1 and 2; Page 2, Paragraph [0030]; Page 3, Paragraph [000051]; Page 5, Paragraph [0078]).

Regarding claim 20, Stegamet further discloses wherein the light emitting material is a polymeric light emitting material (Page 3, Paragraph [0051]).

Art Unit: 2879

Regarding claim 21, Stegamet further discloses wherein the passivation layer directly overlies the layer of material with a work function less than 4 eV (Fig. 2, 260 and 271; Page 4, Paragraphs [0063]-[0064]; Page 5, Paragraph [0078]).

Regarding claim 22, Stegamet further discloses wherein an encapsulation layer overlies the passivation layer (Figs. 1 and 2; Page 1, Paragraph [0007]).

Regarding claim 24, Stegamet further discloses wherein the device further comprises sealing layers of adhesive and glass (Figs. 1 and 2; Page 1, Paragraph [0007]).

Regarding claim 26, Stegamet further discloses wherein the device comprises a substrate, a layer of organic light emitting material, and a transparent cathode comprising a layer of material with a work function less than 4 eV (Page 2, Paragraph [0030]; Page 2, Paragraph [0034]; Page 4, Paragraphs [0063]-[0064]).

Regarding claim 27, Stegamet further discloses wherein the passivation layer is deposited directly onto the layer of material with a work function less than 4 eV (Fig. 2, 260 and 271; Page 4, Paragraphs [0063]-[0064]; Page 5, Paragraph [0078]).

Regarding claim 28, Stegamet further discloses depositing an encapsulating layer onto the passivation layer (Figs. 1 and 2; Page 1, Paragraph [0007]).

Regarding claim 29, Stegamet further discloses wherein the encapsulating layer comprises glass (Figs. 1 and 2; Page 1, Paragraph [0007]). Note that the Examiner understands that glass is inherently SiO₂.

Regarding claim 32, Stegamet further discloses wherein the device is sealed with an adhesive and glass (Figs. 1 and 2; Page 1, Paragraph [0007]).

Art Unit: 2879

Regarding claim 33, Stegamet further discloses adapting the thickness of the passivation layer to energy of electrons, ions, or fields from which protection is required (Figs. 7 and 8; Page 6, Paragraph [0100]).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claim 25 is rejected under 35 U.S.C. 103(a) as being unpatentable over Stegamet (US 2004/0046500) in view of Shi et al. (US 5998805).

Regarding claim 25, Stegamet teaches the invention of claim 24 but is silent regarding the type of adhesive. In the same field of endeavor, Shi teaches an adhesive for attaching a glass encapsulation layer to an organic electroluminescent device, like that of Stegamet, as epoxy resin in order to secure and align the upper substrate to the device closely (Column 7, line 65 to Column 8, line 12). Therefore, it would have been obvious to one of ordinary skill in the art to modify the invention of Stegamet to have the adhesive be epoxy resin in order to secure and align the upper substrate to the device closely, as disclosed by Shi.

Claims 30 and 31 are rejected under 35 U.S.C. 103(a) as being unpatentable over Stegamet (US 2004/0046500) in view of Tai et al. (US 6656611).

Art Unit: 2879

Regarding claims 30 and 31, Stegamet teaches the invention of claim 28 including an encapsulation layer of SiO₂, but is silent regarding the method of forming the encapsulation layer. In the same field of endeavor of methods of forming SiO₂ layers for organic electroluminescent devices, Tai teaches wherein SiO₂ layers are suitably formed by either electron beam evaporation or sputtering in order to form the SiO₂ through a vacuum deposition process (Column 5, lines 30-33). Therefore, it would have been obvious to one of ordinary skill in the art to modify the invention of Stegamet to have the encapsulation layer of SiO₂ be formed through either electron beam evaporation or sputtering in order to form the SiO₂ through a vacuum deposition process, as disclosed by Tai.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Anne M. Hines whose telephone number is (571) 272-2285. The examiner can normally be reached on Monday through Friday from 8:00-4:30.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nimesh Patel can be reached on (571) 272-2457. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Art Unit: 2879

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Anne M Hines Patent Examiner

Art Unit 2879

MARICELI SANTIAGO PRIMARY EXAMINER